

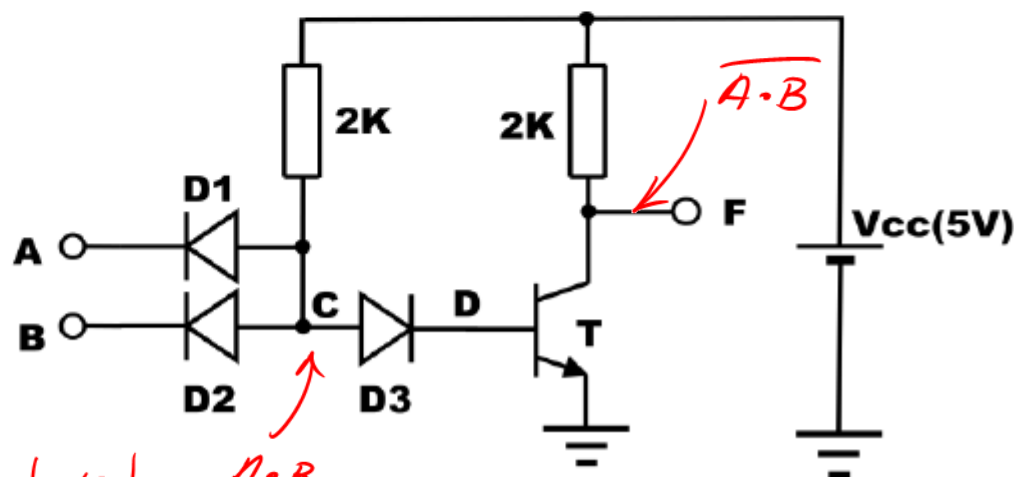
CH1. BASIC SEMICONDUCTOR DEVICES

41. The following circuit implements a two-input logic gate: A and B are the inputs and F the output (F):

a) Obtain the truth table of the circuit and infer which type of logic gate is. Inputs ("1" \rightarrow 5V; "0" \rightarrow 0V)

b) Calculate approximately the voltage in the signaled points and the current of all branches, for each combination of inputs.

DATA: $V_{BE(ON)} = 0.7V$; $V_{CE(SAT)} = 0.2V$, $\beta=50$. Diodes: $V_\gamma=0.7V$

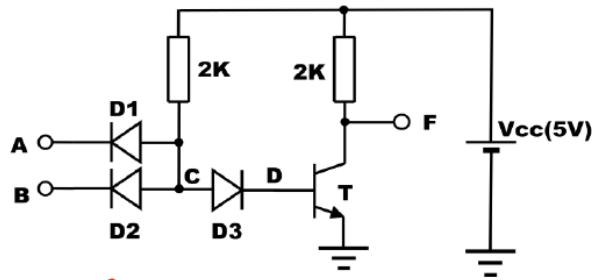


a)

A	B	D ₁	D ₂	C	T	F
0	0	ON	ON	0	OFF	1
0	1	ON	OFF	0	OFF	1
1	0	OFF	ON	0	OFF	1
1	1	OFF	OFF	1	ON	0

$$F = \overline{A \cdot B} \quad (\text{NAND})$$

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$$\beta = 50$$

$$b1) A = B = 1$$

$$\left. \begin{array}{l} D1 \text{ OFF} \\ D2 \text{ OFF} \end{array} \right\} \Rightarrow$$

$D3 \text{ ON}, T \text{ ON, as}$

$$V_{CC} > V_{fD3} + V_{BE(ON)T}$$

$$I_B = \frac{V_{CC} - V_{fD3} - V_{BE(ON)}}{2K} = \frac{5 - 0.7 - 0.7}{2K} = 1.8 \text{ mA}$$

$$\text{Assume } T \text{ saturated} \Rightarrow I_{C(SAT)} = \frac{V_{CC} - V_{CE(SAT)}}{2K} = \frac{5 - 0.2}{2}$$

$$I_{C(SAT)} = 2.4 \text{ mA}$$

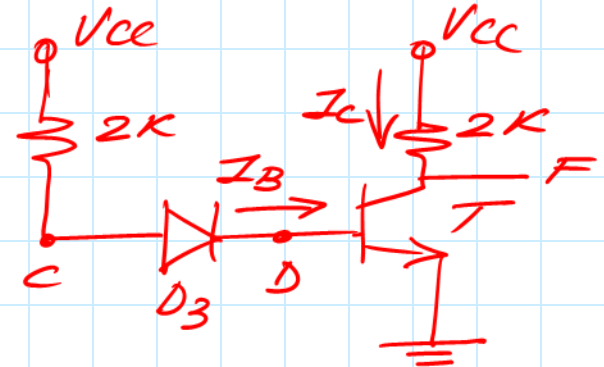
$$\text{As } \beta I_B = 50 \cdot 1.8 > I_{C(SAT)} = 2.4 \text{ mA} \Rightarrow T \text{ is SATURATED}$$

and

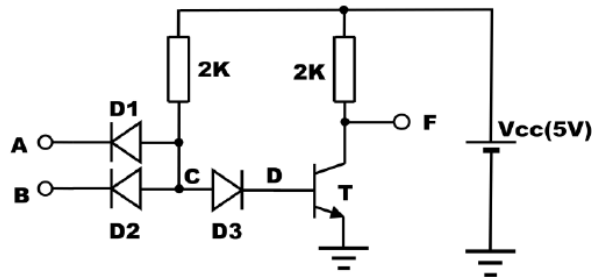
$$V_F = V_{CE(SAT)} = 0.2 \text{ V}$$

$$V_C = V_f + V_{BE(ON)} = 1.4 \text{ V}$$

$$V_D = V_{BE(ON)} = 0.7 \text{ V}$$

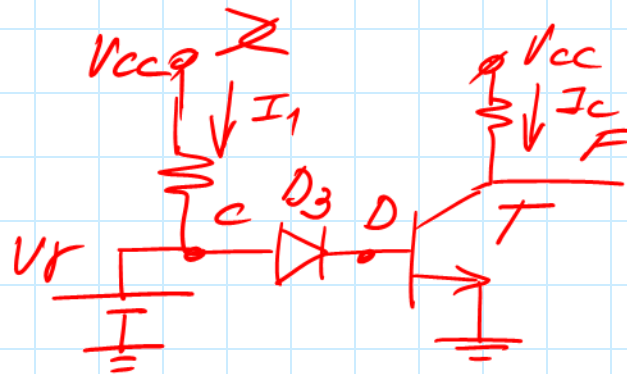


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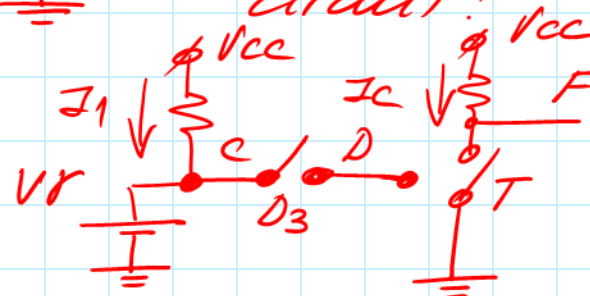
b2) $A=0; B=1$
 $A=1; B=0$
 $A=0; B=0$ } In these cases, at least one diode is ON \Rightarrow

$$V_c = V_f = 0.7V$$



As $V_c < V_f + V_{BE(ON)} \Rightarrow$ $\left. \begin{array}{l} D3 \text{ OFF} \\ T \text{ OFF} \end{array} \right\}$

Then we have the (new) equivalent circuit:



$$V_F = V_{CC}$$

$V_D < V_c$ (in fact, D is open, a floating voltage between $(0 - V_c)$)

$$I_1 = \frac{V_{cc} - V_r}{2K} = \underline{2.15 \text{ mA}}$$

$$I_c = \underline{0 \text{ mA}}$$